

## PCM AMI Line Receiver and Clock Recovery Circuit

### GENERAL DESCRIPTION

The XR-T5740 is a monolithic bipolar IC designed for T1 line receiver application operating at 1.544 M bit/s. It provides all the active circuitry required to perform automatic line build out (ALBO), threshold detection, binary NRZ data and clock recovery as the XR-T5640 but with a crystal filter instead of a LC tank circuit.

A clock recovery using an LC filter circuit version of the XR-T5740 is also available as the XR-T5640.

### FEATURES

- Clock Recovery using Crystal Filter
- On-chip NRZ Data and Clock Recovery Circuitry
- Less than 10 ns Sampling Pulse Over the Operating Range
- Triple Matched ALBO Ports
- Single 5.1 V Power Supply

### APPLICATIONS

- T1 PCM Line Receiver
- T1C PCM Line Receiver (requires external gain)
- General Purpose Bipolar Line Receiver

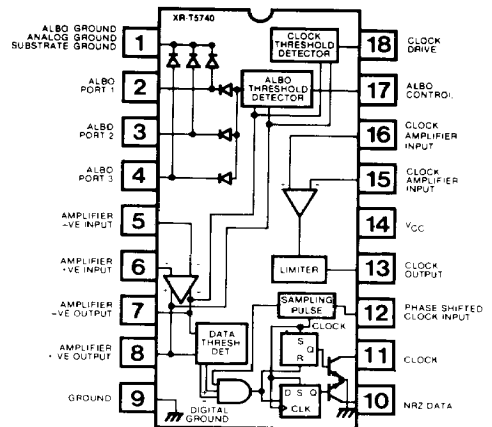
### ABSOLUTE MAXIMUM RATINGS

Storage Temperature	- 65°C to + 150°C
Operating Temperature	- 40°C to + 85°C
Supply Voltage	- 0.5 to + 10V
Supply Voltage Surge (10 ms only)	+ 25V
Input Voltage (except Pins 2,3,4,17)	- 0.5 to + 7V
Input Voltage (Pins 2,3,4,17)	- 0.5 to + 0.5V
Data and Clock Output Voltage	- 0.5 to 20V
Voltage Sure (Pins 5,6,10,11) (10 ms only)	+ 50V

### ORDERING INFORMATION

Part Number	Package	Operating Temperature
XR-T5740	Ceramic	- 40°C to + 85°C

### FUNCTIONAL BLOCK DIAGRAM



### SYSTEM DESCRIPTION

The XR-T5740 is designed as a receiver for interfacing T1 PCM carrier lines on plastic or pulp insulated cables. It can also be used as a general purpose alternate mark inversion (AMI) receiver.

The XR-T5740 is a modified version of XR-T5720 PCM repeater IC. It contains all the active circuitry needed to build a T1 receiver for interfacing up to 6300 ft. The preamplifier, the clock amplifier, threshold detectors, ALBO port, data latches and output drivers are similar to the ones on XR-T5720. Clock extraction is done by means of a crystal filter circuit.

Bipolar +1 and -1 pulses are combined within the IC to form a binary non-return to zero PCM signal at Pin 10. A synchronous clock signal is made available at Pin 11. Both outputs have open collector transistors.

# XR-T5740

## ELECTRICAL CHARACTERISTICS

Test Conditions:  $T_A = 25^\circ\text{C}$ ,  $V_{CC} = 5.1\text{ V} \pm 5\%$

PARAMETERS	MIN	TYP	MAX	UNIT	CONDITIONS
Supply Current		22	30	mA	ALBO Off
Clock & Data Output Leakage Current		0	100	$\mu\text{A}$	$V_{\text{pull-up}} = 15\text{V}$
Amplifier Pin Voltages	2.4	2.9	3.4	V	At Unity DC Gain
Amplifier Output Voltage Swing	2.2			V	
Amplifier Output Offset Voltage	-50	0	50	mV	$R_S = 8.2\text{ k}\Omega$
Amplifier Input Bias Current			5	$\mu\text{A}$	
ALBO on Current	3			mA	
Drive Current		1		mA	
<b>AC CHARACTERISTICS</b>					
Pre-Amplifier					
AC Gain at 1 MHz	20	50		dB	Open Loop
Input Impedance			200	$\text{k}\Omega$	
Output Impedance				$\Omega$	
Clock Amplifier					
AC Gain		32		dB	Open Loop
-3 dB Bandwidth	10			MHz	
Delay		10		ns	
Output Impedance			200	$\Omega$	
<b>ALBO</b>					
Off Impedance	20			$\text{k}\Omega$	
On Impedance			25	$\Omega$	
<b>CLOCK DATA OUTPUT BUFFERS</b>					
$R_L = 130\Omega$ , $V_{\text{pull-up}} = 5.1\text{ V} \pm 5\%$					
Rise Time		30		ns	
Fall Time		30		ns	
Output Pulse Width		244		ns	
Sample Pulse Width		10		ns	
$V_{OL}$		0.7		V	
$I_L$ sink		35		mA	
<b>THRESHOLDS</b>					
ALBO	1.4	1.5	1.6	V	At $V_O = V_{\text{ALBO Threshold}}$
Clock Drive Current Peak		1.0		mA	
Clock Thresholds % of ALBO	63		75	%	
Data Threshold % of ALBO	40	46	52	%	